

## CRYSTAL OSCILLATOR SPXO

# SG-615 series SG-531 / SG-51 series

- Frequency range : 1.025 MHz to 135 MHz
- Supply voltage : 3.3 V / 5.0 V
- Function : Output enable(OE) or Standby( $\overline{ST}$ )
- Pin compatible with full-size metal can. (SG-51 series)
- Pin compatible with half-size metal can. (SG-531 series)



Product Number (please contact us)

SG-615 : Q33615xx1xxxx00

SG-531 : Q32531xx1xxxx00

SG-51 : Q32510xx1xxxx00



Actual size

SG-615



SG-531



SG-51



### Specifications (characteristics)

Item	Symbol	Specifications			Remarks
		SG-615P SG-531P SG-51P	SG-615PTJ SG-531PTJ SG-51PTJ	SG-615PH SG-531PH SG-51PH	
Output frequency range	$f_0$	1.025 MHz to 26 MHz	26.001 MHz to 66.667 MHz		
Supply voltage	$V_{CC}$	5.0 V $\pm$ 0.5 V			
Temperature range	Storage temperature	$T_{stg}$ -55 °C to +125 °C			Store as bare product after unpacking
	Operating temperature	$T_{use}$ -20 °C to +70 °C			
Frequency tolerance	$f_{tol}$	B: $\pm 50 \times 10^{-6}$ , C: $\pm 100 \times 10^{-6}$			-20 °C to +70 °C *1
Current consumption	$I_{CC}$	23 mA Max.	35 mA Max.		No load condition
Disable current	$I_{dis}$	12 mA Max.	28 mA Max.	20 mA Max.	OE=GND
Symmetry	SYM	40 % to 60 %	—	40 % to 60 %	CMOS load: 50 % $V_{CC}$ level TTL load: 1.4 V level
		40 % to 60 %	45 % to 55 %	—	
High output voltage	$V_{OH}$	$V_{CC}$ -0.4 V Min.	2.4 V Min.	$V_{CC}$ -0.4 V Min.	$I_{OH}$ =-400 $\mu$ A(P,PTJ)/-4 mA(PH)
Low output voltage	$V_{OL}$	0.4 V Max.			$I_{OL}$ =16 mA(P)/ 8 mA(PTJ)/ 4 mA(PH)
Output load condition (TTL)	$L_{TTL}$	10 TTL Max.	5 TTL Max.	—	$L_{CMOS} \leq 15$ pF
Output load condition (CMOS)	$L_{CMOS}$	50 pF Max.	—	50 pF Max.	
	Output enable / disable input voltage	$V_{IH}$	2.0 V Min.	3.5 V Min.	80 % $V_{CC}$ Min.
	$V_{IL}$	0.8 V Max.	1.5 V Max.	20 % $V_{CC}$ Max.	$I_{IL}$ = -100 $\mu$ A Min. (OE=GND), PTJ: $I_{IL}$ = -500 $\mu$ A Min. (OE=GND)
Rise time / Fall time	$t_r / t_f$	8 ns Max.	—	7 ns Max.	CMOS load: 20 % $V_{CC}$ to 80 % $V_{CC}$ level TTL load: 0.4 V to 2.4 V level
		8 ns Max.	5 ns Max.	—	
Start-up time	$t_{str}$	4 ms Max.	10 ms Max.		Time at minimum supply voltage to be 0 s
Frequency aging	$f_{aging}$	$\pm 5 \times 10^{-6}$ / year Max.			+25 °C, $V_{CC}$ =5.0 V, First year

\*1 "B" tolerance will be available up to 55 MHz.

### Specifications (characteristics)

Item	Symbol	Specifications			Remarks
		SG-615PCG SG-531PCG	SG-615SCG SG-531SCG	SG-615PCN	
Output frequency range	$f_0$	1.500 MHz to 26.000 MHz		26.001 MHz to 66.667 MHz	
Supply voltage	$V_{CC}$	2.7 V to 3.6 V		3.0 V to 3.6 V	
Temperature range	Storage temperature	$T_{stg}$ -55 °C to +125 °C			Store as bare product after unpacking
	Operating temperature	$T_{use}$ -40 °C to +85 °C			
Frequency tolerance	$f_{tol}$	B: $\pm 50 \times 10^{-6}$ C: $\pm 100 \times 10^{-6}$ M: $\pm 100 \times 10^{-6}$			-20 °C to +70 °C -40 °C to +85 °C
Current consumption	$I_{CC}$	12 mA Max.		20 mA Max.	No load condition
Disable current	$I_{dis}$	10 mA Max.	—	10 mA Max.	OE=GND (PCG,PCN)
Stand-by current	$I_{std}$	—	50 $\mu$ A Max.	—	$\overline{ST}$ =GND (SCG)
Symmetry	SYM	45 % to 55 %			50 % $V_{CC}$ level, $L_{CMOS}$ =Max.
High output voltage	$V_{OH}$	$V_{CC}$ -0.4 V Min.		$V_{CC}$ -0.4 V Min.	$I_{OH}$ =-8 mA
Low output voltage	$V_{OL}$	0.4 V Max.		0.4 V Max.	$I_{OL}$ = 8 mA
Output load condition	$L_{CMOS}$	25 pF Max.		15 pF Max.	
Output enable / disable input voltage	$V_{IH}$	70 % $V_{CC}$ Min.		70 % $V_{CC}$ Min.	OE Terminal or $\overline{ST}$ Terminal
	$V_{IL}$	20 % $V_{CC}$ Max.		30 % $V_{CC}$ Max.	
Rise time / Fall time	$t_r / t_f$	4 ns Max.			20 % $V_{CC}$ to 80 % $V_{CC}$ level, $L_{CMOS} \leq$ Max.
Start-up time	$t_{str}$	12 ms Max.		10 ms Max.	$t=0$ at 90% $V_{CC}$
Frequency aging	$f_{aging}$	$\pm 5 \times 10^{-6}$ / year Max.			+25 °C, $V_{CC}$ =3.3 V, First year



## Specifications (characteristics)

Item	Symbol	Specifications			Remarks
		SG-615PTW / STW SG-531PTW / STW	SG-615PHW / SHW SG-531PHW / SHW	SG-615PCW / SCW SG-531PCW / SCW	
Output frequency range	$f_0$	55.001 MHz to 135.000 MHz		26.001 MHz to 135.000 MHz	
Supply voltage	$V_{cc}$	5.0 V $\pm$ 0.5 V		3.3 V $\pm$ 0.3 V	
Temperature range	Storage temperature	-55 °C to +125 °C			Store as bare product after unpacking
	Operating temperature	-20 °C to +70 °C		-40 °C to +85 °C	
Frequency tolerance	$f_{tol}$	B: $\pm 50 \times 10^{-6}$ , C: $\pm 100 \times 10^{-6}$		M: $\pm 100 \times 10^{-6}$	-20 °C to +70 °C *1
		—		—	-40 °C to +85 °C
Current consumption	$I_{cc}$	45 mA Max.		28 mA Max.	No load condition( Max. frequency range )
Disable current	$I_{dis}$	30 mA Max.		16 mA Max.	OE=GND (PTW,PHW,PCW)
Stand-by current	$I_{std}$	50 $\mu$ A Max.		—	$\overline{ST}$ =GND (STW,SHW,SCW)
Symmetry	SYM	—		40 % to 60 %	50 % $V_{cc}$ level, L_CMOS=Max.
		40 % to 60 %		—	1.4 V level, L_CMOS=Max.
High output voltage	$V_{OH}$	$V_{cc}$ -0.4 V Min.			$I_{OH}$ =-16 mA(PTW,STW,PHW,SHW), -8 mA(PCW,SCW)
Low output voltage	$V_{OL}$	0.4 V Max.			$I_{OL}$ = 16 mA(PTW,STW,PHW,SHW), 8 mA(PCW,SCW)
Output load condition (TTL)	$L_{TTL}$	5 TTL Max.	—	—	$f_0 \leq 90$ MHz, Max.supply voltage
Output load condition (CMOS)	$L_{CMOS}$	15 pF Max.			Max.frequency, Max.supply voltage
Output enable / disable input voltage	$V_{IH}$	2.0 V Min.		70 % $V_{cc}$ Min.	OE Terminal or $\overline{ST}$ Terminal
	$V_{IL}$	0.8 V Max.		20 % $V_{cc}$ Max.	
Rise time / Fall time	$t_r / t_f$	—		4 ns Max.	20 % $V_{cc}$ to 80 % $V_{cc}$ level, L_CMOS $\leq$ Max.
		4 ns Max.		—	
Start-up time	$t_{str}$	10 ms Max.			Time at minimum supply voltage to be 0 s
Frequency aging	$f_{aging}$	$\pm 5 \times 10^{-6}$ / year Max.			+25 °C, $V_{cc}$ =5.0 V / 3.3 V, First year

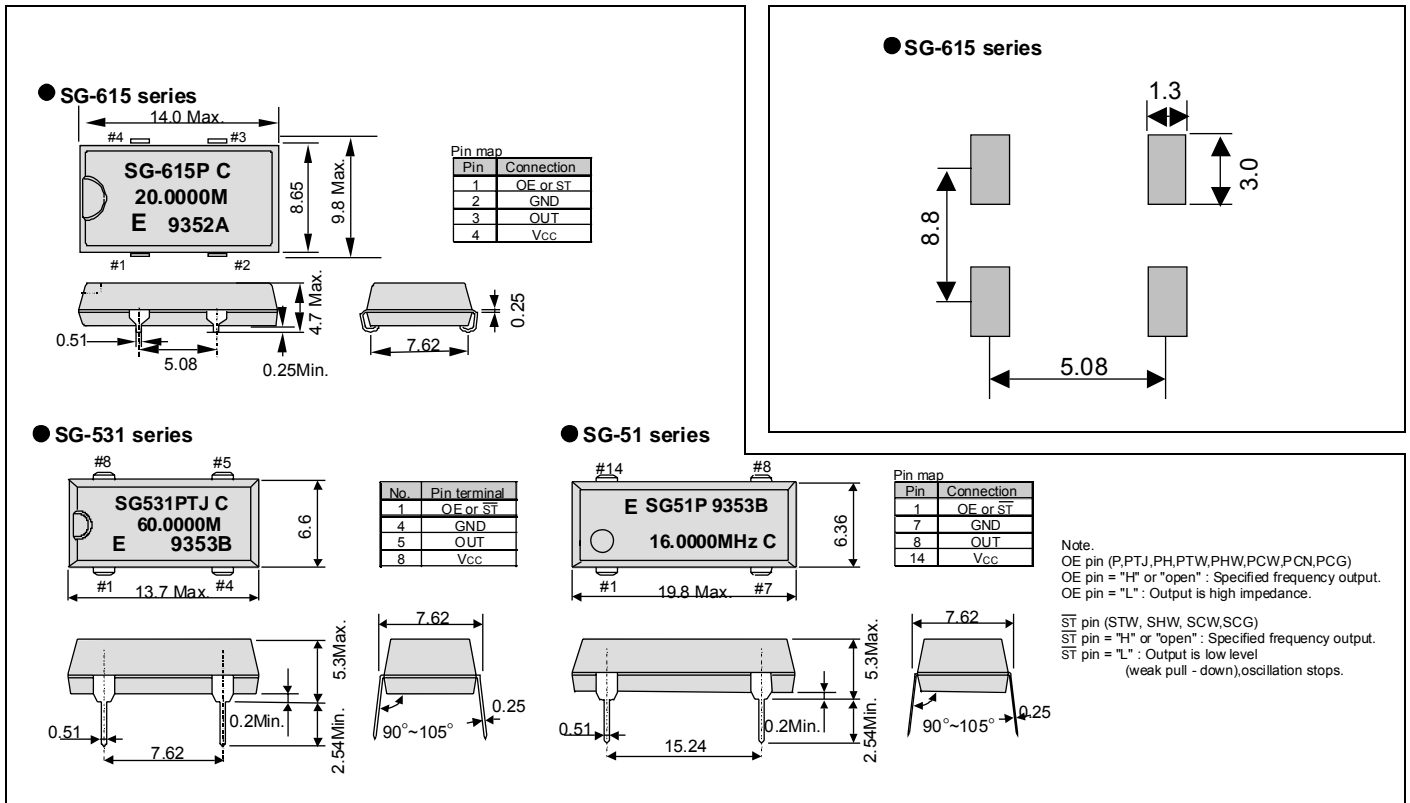
\*1 "C" tolerance :  $f_0 \geq 66.667$  MHz(PTW,STW,PHW,SHW)

## External dimensions

(Unit:mm)

## Footprint (Recommended)

(Unit:mm)



# “QMEMS” EPSON TOYOCOM

In order to meet customer needs in a rapidly advancing digital, broadband and ubiquitous society, we are committed to offering products that are one step ahead of the market and a rank above the rest in quality. To achieve our goals, we follow a “3D (three device) strategy” designed to drive both horizontal and vertical growth. We will to grow our three device categories of “Timing Devices”, “Sensing Devices” and “Optical Devices”, and expand vertical growth through a combination of products from these categories.

A Quartz MEMS is any high added value quartz device that exploits the characteristics of quartz crystal material but that is produced using MEMS (micro-electro-mechanical system) processing technology.

Market needs are advancing faster than previously imagined toward smaller, more stable crystal products, but we will stay ahead of the curve by rolling out products that exceed market speed and quality requirements. We want to further accelerate the 3D strategy by QMEMS.

Quartz devices have become crucial in the network environment where products are increasingly intended for broadband, ubiquitous applications and where various types of terminals can transfer information almost immediately via LAN and WAN on a global scale. Epson Toyocom Corporation addresses every single aspect within a network environment. The new corporation offers “Digital Convergence” solutions to problems arising with products for consumer use, such as, core network systems and automotive systems.



## PROMOTION OF ENVIRONMENTAL MANAGEMENT SYSTEM CONFORMING TO INTERNATIONAL STANDARDS

At Epson Toyocom, all environmental initiatives operate under the Plan-Do-Check-Action(PDCA) cycle designed to achieve continuous improvements. The environmental management system (EMS) operates under the ISO 14001 environmental management standard.

ISO 14000 is an international standard for environmental management that was established by the International Standards Organization in 1996 against the background of growing concern regarding global warming, destruction of the ozone layer and global deforestation

All of our major manufacturing and non-manufacturing sites, in Japan and overseas, completed the acquisition of ISO 14001 certification. In the future, new group companies will be expected to acquire the certification around the third year of operations.

## WORKING FOR HIGH QUALITY

In order to provide high quality and reliable products and services than meet customer needs, Epson Toyocom made early efforts towards obtaining ISO9000 series certification and has acquired ISO9001 for all business establishments in Japan and abroad. We have also acquired ISO/TS 16949 certification that is requested strongly by major automotive manufacturers as standard.

QS-9000 is an enhanced standard for quality assurance systems formulated by leading U.S. automobile manufacturers based on the international ISO 9000 series.

ISO/TS 16949 is a global standard based on QS-9000, a severe standard corresponding to the requirements from the automobile industry.

### ► Explanation of the mark that are using it for the catalog

	<ul style="list-style-type: none"> <li>► Pb free.</li> <li>► Complies with EU RoHS directive.</li> </ul>
	<ul style="list-style-type: none"> <li>► Pb free terminal designed. Contains Pb in products exempted by RoHS directive. (Contains Pb in sealing glass, high melting temperature type solder or other.)</li> <li>► Complies with EU RoHS directive.</li> </ul>
	<ul style="list-style-type: none"> <li>► The products have been designed for high reliability applications such as Automotive.</li> </ul>

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- These products are intended for general use in electronic equipment. When using them in specific applications that require extremely high reliability, such as the applications stated below, you must obtain permission from Epson Toyocom in advance.
  - / Space equipment (artificial satellites, rockets, etc.) / Transportation vehicles and related (automobiles, aircraft, trains, vessels, etc.)
  - / Medical instruments to sustain life / Submarine transmitters / Power stations and related / Fire work equipment and security equipment
  - / traffic control equipment / and others requiring equivalent reliability.
- In this new crystal master for Epson Toyocom, product codes and markings will remain as previously identified prior to the merger. Due to the on-going strategy of gradual unification of part numbers, please review product codes and markings, as they will change during the course of the coming months.

We apologize for the inconvenience, but we will eventually have a unified part numbering system for Epson Toyocom that will be user friendly.